



60V N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

		I _D MAX	
BV _{DSS}	RDS(ON) MAX	T _C = +25°C	
		(Note 9)	
60V	$3.1 \text{m}\Omega$ @ V _{GS} = 10V	100A	

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Switching
- Synchronous Rectification
- DC-DC Converters

Features

- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable And Robust End Application
- Low R_{DS(ON)} Minimizes Power Losses
- Low Q_g Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.

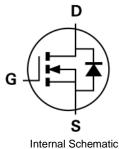
https://www.diodes.com/quality/product-definitions/

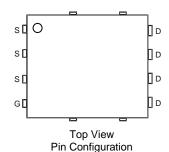
Mechanical Data

- Case: PowerDI®5060-8
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)









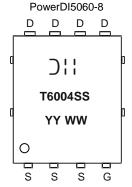
Ordering Information (Note 4)

Part Number	Case	Packaging		
DMT6004SPS-13	PowerDI5060-8	2,500 / Tape & Reel		

Notes:

- 1, EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant, All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



) | = Manufacturer's Marking T6004SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 21 = 2021)WW = Week (01 to 53)

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DMT6004SPS



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit		
Drain-Source Voltage			VDSS	60	V		
Gate-Source Voltage			Vgss	±20	V		
Continuous Drain Current (Note 5)		$T_A = +25$ °C $T_A = +70$ °C	lo	23 18	Α		
Continuous Drain Current (Notes 6 & 9) $T_C = +25^{\circ}C$ $T_C = +70^{\circ}C$		lo	100 100	А			
Maximum Continuous Body Diode Forward Current (Notes 6 & 9)			Is	100	Α		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			Ідм	400	Α		
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			rulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)		Isм	400	А
Avalanche Current, L = 0.2mH			I _{AS}	45	Α		
Avalanche Energy, L = 0.2mH			Eas	200	mJ		

Thermal Characteristics

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)	T _A = +25°C	PD	2.6	W
Thermal Resistance, Junction to Ambient	Steady State	Reja	47	°C/W
Total Power Dissipation (Note 6)	T _C = +25°C	PD	139	W
Thermal Resistance, Junction to Case	Rejc	0.9	°C/W	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

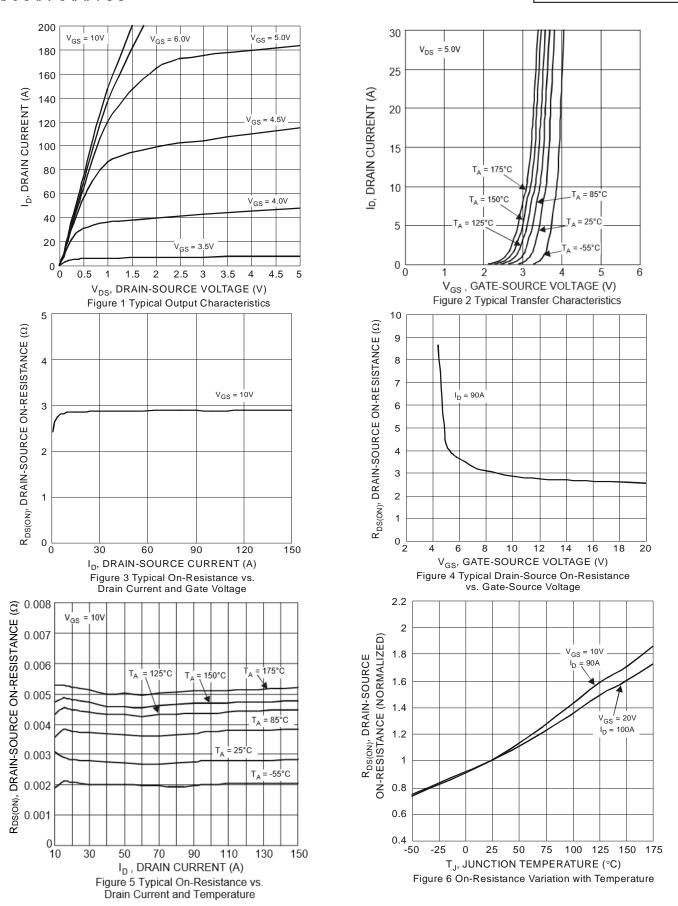
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	1		V	$V_{GS} = 0V$, $I_D = 1mA$	
Zero Gate Voltage Drain Current	I _{DSS}	_	-	1	μA	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	Vgs(TH)	2	2.5	4	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$	
Static Drain-Source On-Resistance	RDS(ON)	_		3.1	mΩ	V _G S = 10V, I _D = 50A	
Diode Forward Voltage	VsD		0.9	1.2	V	V _G S = 0V, I _S = 20A	
DYNAMIC CHARACTERISTICS (Note 8)	DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	4,556			$V_{DS} = 30V$, $V_{GS} = 0V$, $f = 1MHz$	
Output Capacitance	Coss		1,383		pF		
Reverse Transfer Capacitance	Crss	_	105.2				
Gate Resistance	Rg	_	0.7		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge	Qg		95.4			V _{DD} = 30V, I _D = 90A, V _{GS} = 10V	
Gate-Source Charge	Qgs		21.6		nC		
Gate-Drain Charge	Q _{gd}		20.4	_			
Turn-On Delay Time	t _{D(ON)}	_	13.2	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 90A, R_{g} = 3.5\Omega$	
Turn-On Rise Time	t _R	_	11.7	_	ns		
Turn-Off Delay Time	tD(OFF)	_	31	_			
Turn-Off Fall Time	t _F	_	12	_			
Body Diode Reverse Recovery Time	t _{RR}	_	50.5	_	ns	I_ 500 di/dt 1000/up	
Body Diode Reverse Recovery Charge	Qrr		80.8		nC	I _F = 50A, di/dt = 100A/μs	

Notes: 5. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

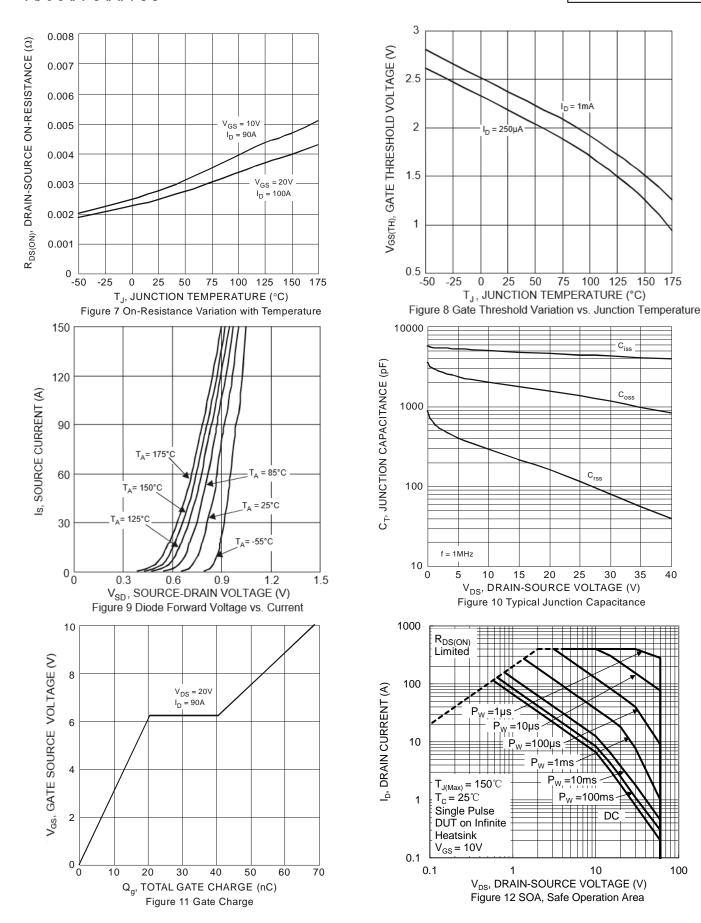
- Device mounted on FX-4 substate FC board, 202 copper, with trieffinal bias to a company.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to production testing.
 Package limited.

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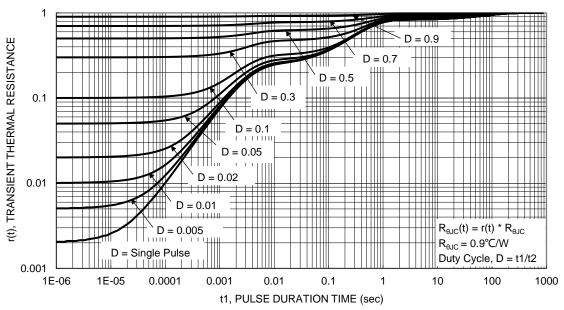


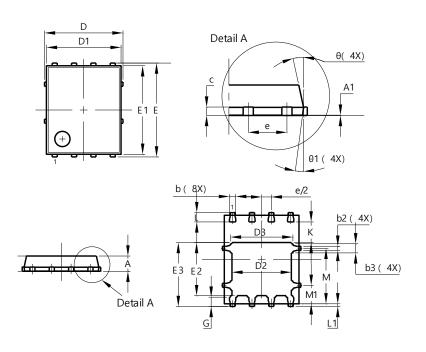
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

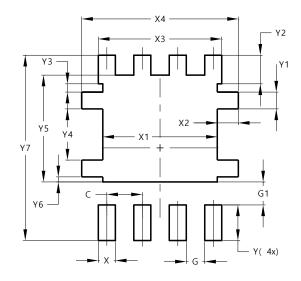


PowerDI5060-8						
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	_			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
С	0.230	0.330	0.277			
D		5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
E	(6.15 BSC				
E1	5.60	5.60 6.00				
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е		1.27 BSC				
G	0.51	0.71	0.61			
K	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
M	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12º	11º			
Θ1	6º	8º	7º			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)			
C	1.270			
G	0.660			
G1	0.820			
X	0.610			
X1	4.100			
X2	0.755			
Х3	4.420			
X4	5.610			
Υ	1.270			
Y1	0.600			
Y2	1.020			
Y3	0.295			
Y4	1.825			
Y5	3.810			
Y6	0.180			
Y7	6.610			



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